

# **DATA SHEET**

THYRISTOR SURGE SUPPRESSORS MODEMS/LINE CARD

P61089B

RoHS compliant & Halogen free







# **Dual Programmable Thyristor Transient Voltage Suppressor** P61089B

## **General Description**

This device has been especially designed to protect 2 new high voltage, as well as classical SLICs, against transient overvoltages.

Positive overvoltages are clamped by 2 diodes. Negative surges are suppressed by 2 thyristors, their breakdown voltage being referenced to -V<sub>BAT</sub> through the gate.

This component presents a very low gate triggering current (I<sub>GT</sub>) in order to reduce the current consumption on printed circuit board during the firing phase.

This devices is not subject to ageing and provide a fail safe mode in short circuit for a better protection. They are used to help equipment to meet various standards such as UL1950, IEC950/CSA C22.2, UL1459 and FCC part68.

#### **Features**

- Dual line programmable transient voltage suppressor
- Wide negative firing voltage range: V<sub>MGL</sub> =-155V
- Holding current: I<sub>H</sub> >150mA
- Marking: H61089B

- Low dynamic switching voltages: V<sub>FP</sub> and V<sub>DGL</sub>
- Low gate triggering current: I<sub>GT</sub> =5mA max
- Halogen Free

Package	Device Symbol		
SOP-8	K1 1 (Tip) 8 K1 (Tip) 7 A (Ground) NC 3 6 A (Ground) K2 (Ring) 5 K2 (Ring)		



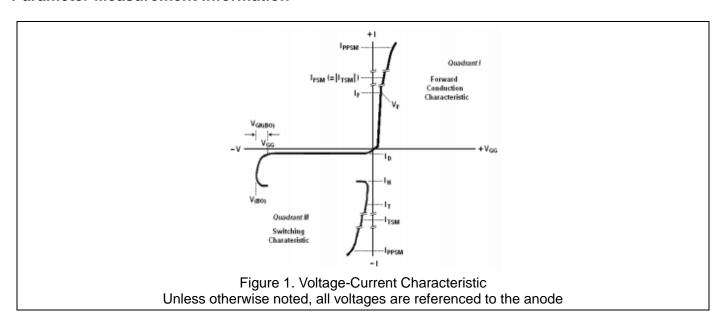
## Absolute Maximum Ratings (T<sub>A</sub>=25℃)

Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage, V <sub>GK</sub> =0	$V_{DRM}$	-170	V
Repetitive peak gate-cathode voltage, V <sub>KA</sub> =0	$V_{GKRM}$	-170	V
Non-repetitive peak on-state current 10/1000µs (Telcordia (Bellcore) GR-1089-CORE.Issue 2.February 1999, Section4) 5/320µs (ITU-T K.20, K.21 & K.45, K.44 open-circuit voltage wave shape 10/700µs) 1.2/50µs (Telcordia (Bellcore) GR-1089-CORE.Issue 2.February 1999, Section4) 2/10µs (Telcordia (Bellcore) GR-1089-CORE.Issue 2.February 1999, Section4)	Іррѕм	30 40 100 120	A
Non-repetitive peak on-state current. VGG=-75V 50Hz to 60Hz 0.1s 1s 5s 300s 900s	Ітѕм	11 4.8 2.7 0.95 0.93	А
Operating free-air temperature range	T <sub>A</sub>	-40 to +85	$^{\circ}$
Operating junction temperature range	TJ	-40 to +125	$^{\circ}$
Storage temperature range	T <sub>STG</sub>	-40 to +150	$^{\circ}$
Lead soldering temperature, 10 seconds	T <sub>LS</sub>	300(Mix.)	$^{\circ}$ C

#### **Thermal Characteristics**

Parameter	Test Conditions	Max	Unit
$R_{\theta JA}$ Junction to free air thermal temperature	T <sub>A</sub> =25°C, EIA/JESD51-3 PCB, EIA/JESD51-2 environment, P <sub>TOT</sub> =1.7W	120	°C/W

#### **Parameter Measurement Information**

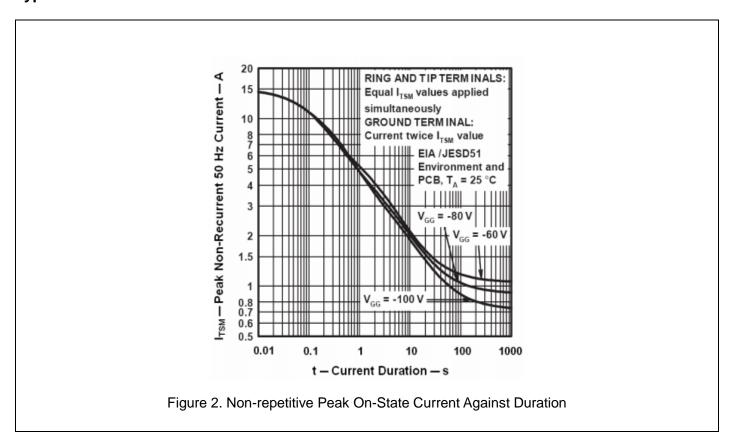




## Electrical Characteristics, Rating at 25℃ unless otherwise specified

Parameter Test Conditions		Min.	Тур.	Max.	Unit		
I <sub>D</sub>	Off-state current	V <sub>D</sub> =V <sub>DRM</sub> , V <sub>GK</sub> =0, V <sub>G2</sub> ≥+5V	T <sub>J</sub> =25 ℃ T <sub>J</sub> =85 ℃			-5 -50	μΑ
V <sub>(BO)</sub>	Breakover voltage	2/10μs, I <sub>PP</sub> =-56A, R <sub>S</sub> =45Ω, V <sub>GG</sub> =-48V 1.2/50μs, I <sub>PP</sub> =-53A, R <sub>S</sub> =47Ω, V <sub>GG</sub> =-48	,		-57 -60		V
V <sub>GK</sub> (BO)	Gate-cathode impulse breakover voltage	2/10μs, I <sub>PP</sub> =-56A, R <sub>S</sub> =45Ω, V <sub>GG</sub> =-48V 1.2/50μs, I <sub>PP</sub> =-53A, R <sub>S</sub> =47Ω, V <sub>GG</sub> =-48	, -		9 12	20	٧
V <sub>F</sub>	Forward voltage	I <sub>F</sub> =5A, T <sub>W</sub> =200μs				3	V
V <sub>FRM</sub>	Peak forward recovery voltage	2/10μs, I <sub>PP</sub> =-56A, R <sub>S</sub> =45Ω, V <sub>GG</sub> =-48V 1.2/50μs, I <sub>PP</sub> =-53A, R <sub>S</sub> =47Ω, V <sub>GG</sub> =-48	,		6 8		V
Ін	Holding current	I <sub>T</sub> =-1A, di/dt=1A/ms, V <sub>GG</sub> =-48V		-150			mA
I <sub>GKS</sub>	Gate reverse current	V <sub>GG</sub> =V <sub>GK</sub> =V <sub>GKRM</sub> , V <sub>KA</sub> =0	T <sub>J</sub> =25℃ T <sub>J</sub> =85℃			-5 -50	μΑ
l <sub>GT</sub>	Gate trigger current	I <sub>T</sub> =-3A, t <sub>p(g)</sub> ≥20μs, V <sub>GG</sub> =-48V				5	mA
V <sub>GT</sub>	Gate-cathode trigger voltage	I <sub>T</sub> =-3A, t <sub>p(g)</sub> ≥20μs, V <sub>GG</sub> =-48V			2.5	4	V
Q <sub>GS</sub>	Gate switching charge	1.2/50μs, I <sub>PP</sub> =-53A, R <sub>S</sub> =47Ω, V <sub>GG</sub> =-48	BV, C <sub>G</sub> =220nF		0.1		μC
Ска	Cathode-anode off- state capacitance	F=1MHz, V <sub>D</sub> =1V, I <sub>G</sub> =0	V <sub>D</sub> =-3V V <sub>D</sub> =-48V			100 50	pF

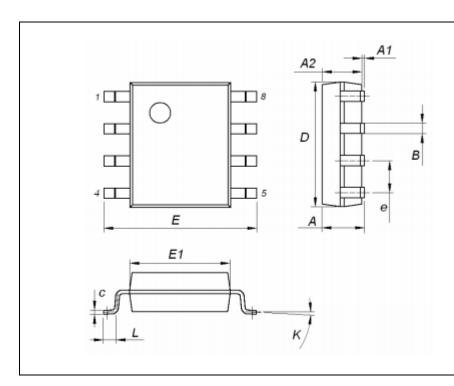
## **Typical Characteristics**





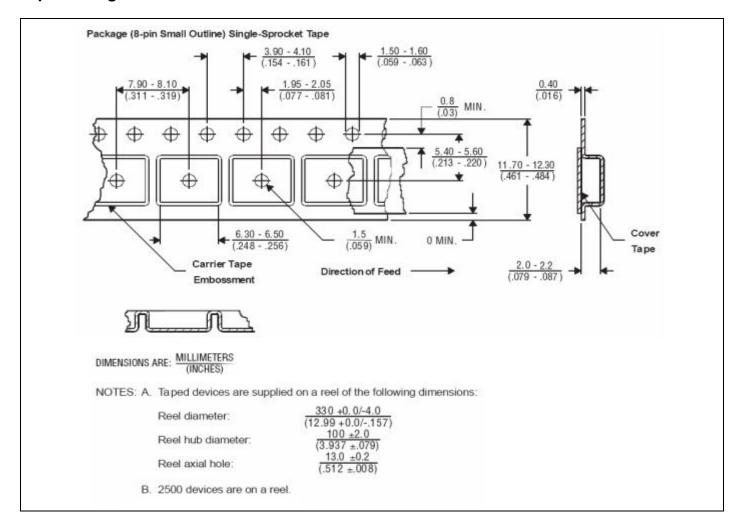
## THYRISTOR SURGE SUPPRESSORS P61089B

## **Dimensions (SOP-8)**



C) (19	ماما	Dimension (mm)			
Syn	Symbol	Min.	Тур.	Max.	
1	4			1.75	
Α	\1	0.10		0.25	
Α	.2	1.35	1.55	1.75	
E	3	0.35	0.42	0.49	
(	2	0.19		0.25	
	)	4.80	4.90	5.00	
E	<b>=</b>	5.80	6.00	6.20	
Е	1	3.80	3.95	4.00	
•	Э		1.27		
I	L	0.40		0.90	
ŀ	<	0°		8°	

## **Tape Package Information**







#### **Circuit Protection Components**

#### LEGAL DISCLAIMER

YAGEO, its distributors and agents (collectively, "YAGEO"), hereby disclaims any and all liabilities for any errors, inaccuracies or incompleteness contained in any product related information, including but not limited to product specifications, datasheets, pictures and/or graphics. YAGEO may make changes, modifications and/or improvements to product related information at any time and without notice.

YAGEO makes no representation, warranty, and/or guarantee about the fitness of its products for any particular purpose or the continuing production of any of its products. To the maximum extent permitted by law, YAGEO disclaims (i) any and all liability arising out of the application or use of any YAGEO product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for a particular purpose, non -infringement and merchantability.

YAGEO products are designed for general purpose applications under normal operation and usage conditions. Please contact YAGEO for the applications listed below which require especially high reliability for the prevention of defects which might directly cause damage to the third party's life, body or property: Aerospace equipment (artificial satellite, rocket, etc.), Atomic energy-related equipment, Aviation equipment, Disaster prevention equipment, crime prevention equipment, Electric heating apparatus, burning equipment, Highly public information network equipment, data-processing equipment, Medical devices, Military equipment, Power generation control equipment, Safety equipment, Traffic signal equipment, Transportation equipment and Undersea equipment, or for any other application or use in which the failure of YAGEO products could result in personal injury or death, or serious property damage. Particularly YAGEO Corporation and its affiliates do not recommend the use of commercial or automotive grade products for high reliability applications or manned space flight.

Information provided here is intended to indicate product specifications only. YAGEO reserves all the rights for revising this content without further notification, as long as products are unchanged. Any product change will be announced by PCN.



